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2SC5200/FJL4315 NPN Epitaxial Silicon Transistor

Applications

- High-Fidelity Audio Output Amplifier
- General Purpose Power Amplifier

Features

- High Current Capability: $I_C = 17A$.
- High Power Dissipation : 150watts.
- High Frequency : 30MHz.
- High Voltage : V_{CEO}=250V
- Wide S.O.A for reliable operation.
- Excellent Gain Linearity for low THD.
- Complement to 2SA1943/FJL4215.
- Thermal and electrical Spice models are available.
- Same transistor is also available in:
 - -- TO3P package, 2SC5242/FJA4313 : 130 watts
 - -- TO220 package, FJP5200 : 80 watts
 - -- TO220F package, FJPF5200 : 50 watts

TO-264 1.Base 2.Collector 3.Emitter

January 2009

Absolute Maximum Ratings*	T _a = 25°C unless otherwise noted
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Symbol	Parameter	Ratings	Units
BV _{CBO}	Collector-Base Voltage	250	V
BV _{CEO}	Collector-Emitter Voltage	250	V
BV _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current(DC)	17	А
I _B	Base Current	1.5	А
P _D	Total Device Dissipation(T _C =25°C) Derate above 25°C	150 1.04	W W/°C
T _J , T _{STG}	Junction and Storage Temperature	- 50 ~ +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

$\label{eq:thermal} Thermal \ Characteristics^* \quad {\tt T_a=25^{\circ}C} \ {\tt unless \ otherwise \ noted}$

Symbol	Parameter	Max.	Units	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	0.83	°C/W	

* Device mounted on minimum pad size

h_{FE} Classification

Classification	R	0
h _{FE1}	55 ~ 110	80 ~ 160

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =5mA, I _E =0	250			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=10mA$, $R_{BE}=\infty$	250			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =5mA, I _C =0	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =230V, I _E =0			5.0	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} =5V, I _C =0			5.0	μΑ
h _{FE1}	DC Current Gain	V _{CE} =5V, I _C =1A	=5V, I _C =1A 55		160	
h _{FE2}	DC Current Gain	V _{CE} =5V, I _C =7A	35	60		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =8A, I _B =0.8A		0.4	3.0	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =5V, I _C =7A	1.0		1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =5V, I _C =1A		30		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz		200		pF

* Pulse Test: Pulse Width=20µs, Duty Cycle≤2%

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
2SC5200RTU	C5200R	TO-264	TUBE	hFE1 R grade
2SC5200OTU	C5200O	TO-264	TUBE	hFE1 O grade
FJL4315RTU	J4315R	TO-264	TUBE	hFE1 R grade
FJL4315OTU	J4315O	TO-264	TUBE	hFE1 O grade

Typical Characteristics

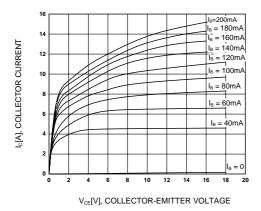


Figure 1. Static Characteristic

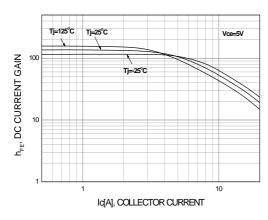


Figure 3. DC current Gain (O grade)

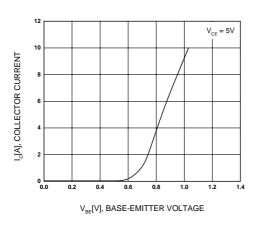


Figure 5. Base-Emitter On Voltage

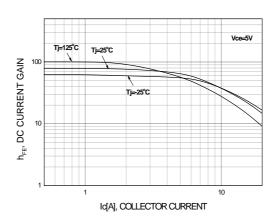


Figure 2. DC current Gain (R grade)

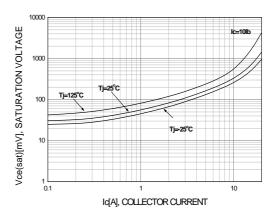
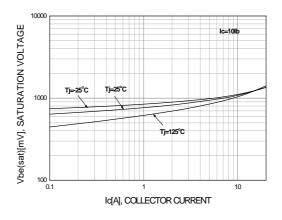


Figure 4. Collector-Emitter Saturation Voltage





Typical Characteristics 1.0 100 Transient Thermal Resistance, $R_{\rm thjc} {\rm l}^{\rm o} {\rm C}$ / W] I_c MAX. (Pulsed*) 0.9 I_c [A], COLLECTOR CURRENT 0.8 10ms* 10 0.7 I_c Max. (DC) 100ms 0.6 DC 0.5 0.4 0.3 0.1 0.2 *SINGLE NONREPETITIVE 0.1 PULSE $T_c=25[°C]$ 0.01 1E-6 1E-5 1E-4 1E-3 0.01 0.1 10 100 Pulse duration [sec] V_{CE} [V], COLLECTOR-EMITTER VOLTAGE Figure 7. Power Derating Figure 8. Safe Operating Area 160

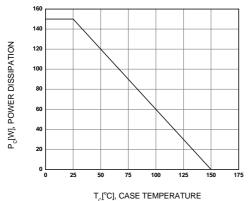
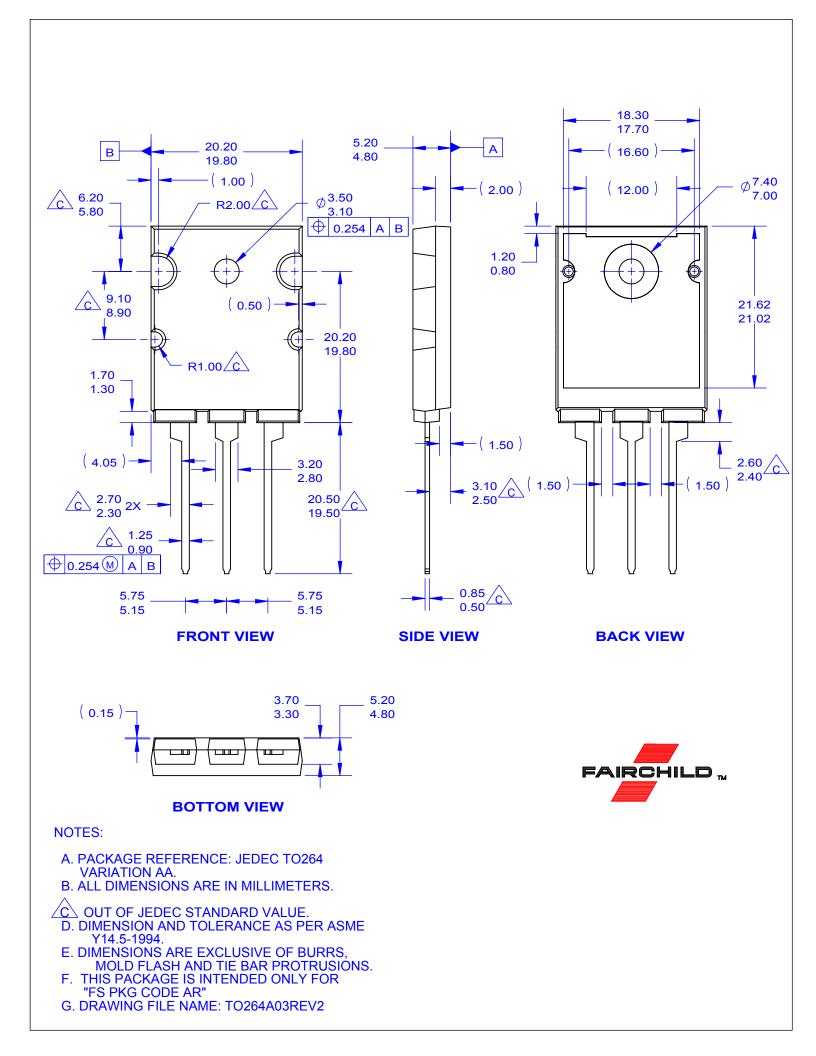


Figure 9. Power Derating



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